

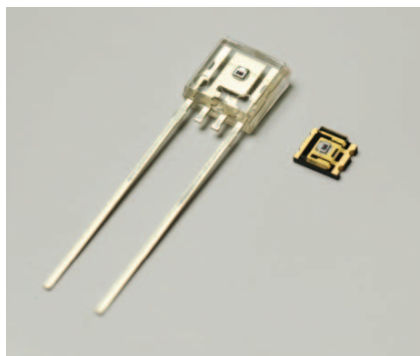


Photo IC diodes

S9066-211SB S9067-201CT

Spectral response close to human eye sensitivity

The S9066-211SB, S9067-201CT photo ICs have spectral response close to human eye sensitivity. Two photosensitive areas are made on a single chip. One is for detecting light in the visible to near infrared range and the other is only sensitive to near infrared light and used for output signal correction. Almost only the visible range can be measured by finding the difference between the two output signals in the internal current amplifier circuit. Compared to previously available devices, these photo ICs offer lower output fluctuations for light sources producing the same illuminance at different color temperatures.

Features

- ➔ Spectral response close to human eye sensitivity is attained without using visual-compensated filter.
- ➔ Operation just as easy to use as a photodiode
- ➔ Large output current equivalent to phototransistors
- ➔ Lower output-current fluctuations
- ➔ Excellent linearity
- ➔ Low output fluctuations for light sources producing the same illuminance at different color temperatures

Applications

- ➔ Energy-saving sensor for TVs, etc.
- ➔ Light dimmers for liquid crystal panels
- ➔ Cellular phone backlight dimmers
- ➔ Various types of light level measurement

Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Condition	S9066-211SB	S9067-201CT	Unit
Reverse voltage	VR		-0.5 to +12		V
Photocurrent	IL		5		mA
Forward current	IF		5		mA
Power dissipation*1	P		250	150	mW
Operating temperature	Topr	No dew condensation*2	-30 to +80		°C
Storage temperature	Tstg	No dew condensation*2	-40 to +85		°C

*1: Power dissipation decreases at a rate of the following rate above Ta=25 °C.
S9066-211SB: 3.3 mW/°C, S9067-201CT: 2.0 mW/°C

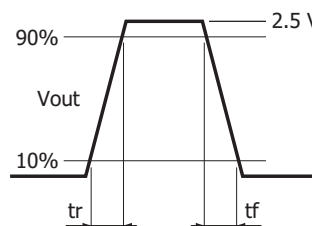
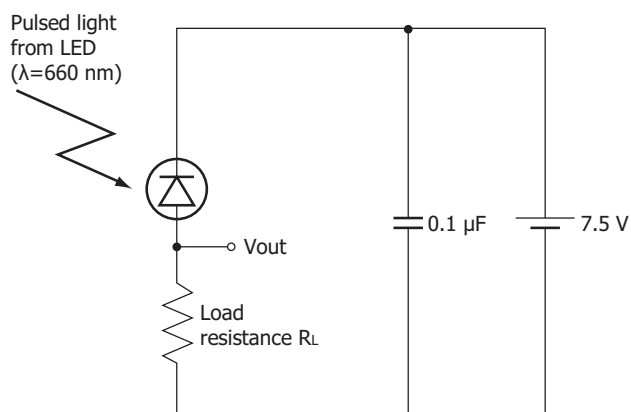
*2: When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Ta=25 °C)

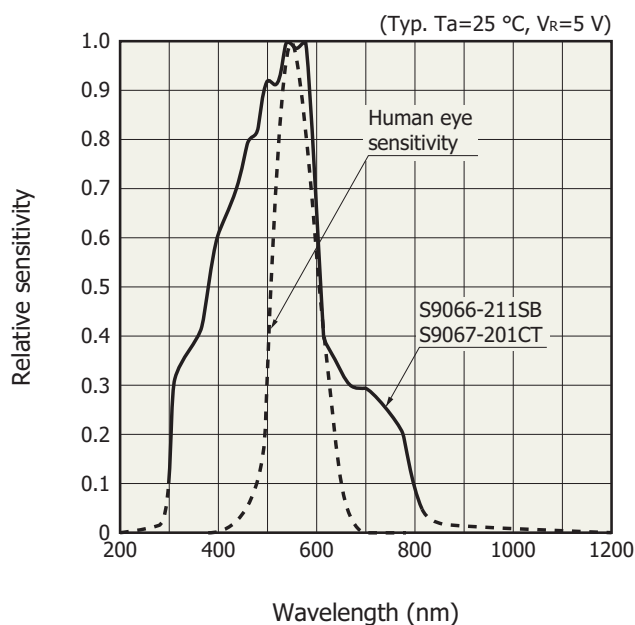
Parameter	Symbol	Condition	S9066-211SB			S9067-201CT			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Spectral response range	λ		300 to 820			300 to 820			nm
Peak sensitivity wavelength	λ_p		-	560	-	-	560	-	nm
Dark current	I_D	$V_R=5\text{ V}$	-	1.0	50	-	1.0	50	nA
Photocurrent	I_L	$V_R=5\text{ V}$, 2856 K, 100 lx	0.19	-	0.35	0.18	-	0.34	mA
Rise time*3	t_r	10 to 90%, $V_R=7.5\text{ V}$	-	6.0	-	-	6.0	-	ms
Fall time*3	t_f	$R_L=10\text{ k}\Omega$, $\lambda=560\text{ nm}$	-	2.5	-	-	2.5	-	ms

*3: Rise/fall time measurement method



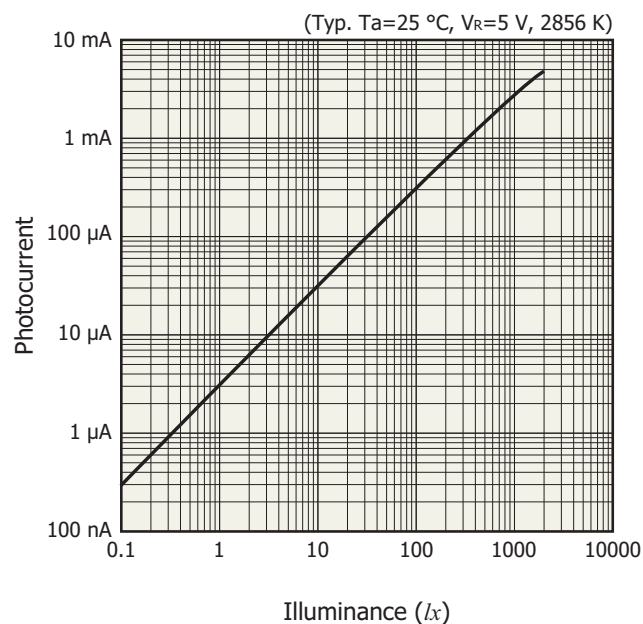
KPIC0041EB

Spectral response



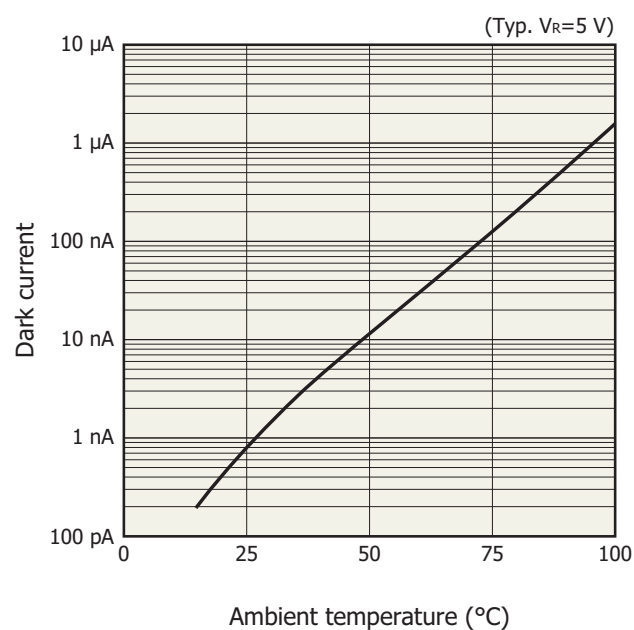
KPIC80078ED

Photocurrent vs. illuminance

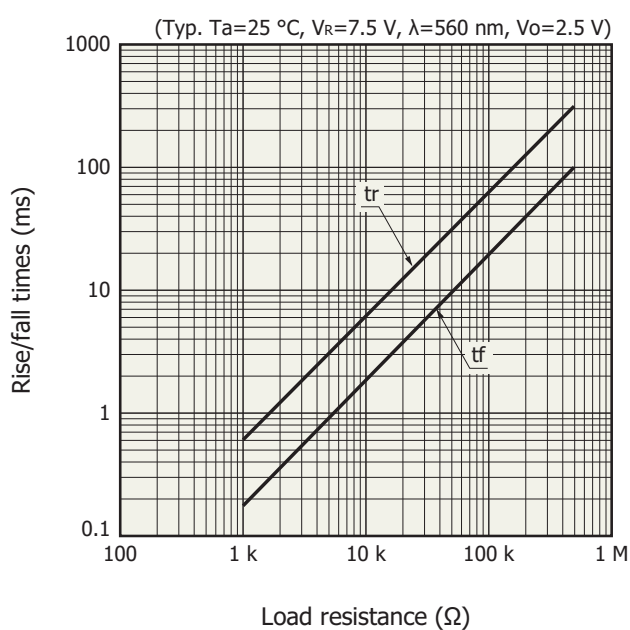


KPIC80083EC

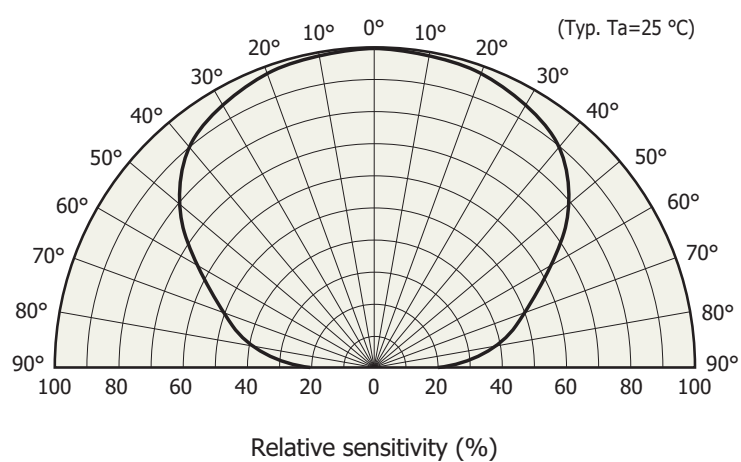
Dark current vs. ambient temperature



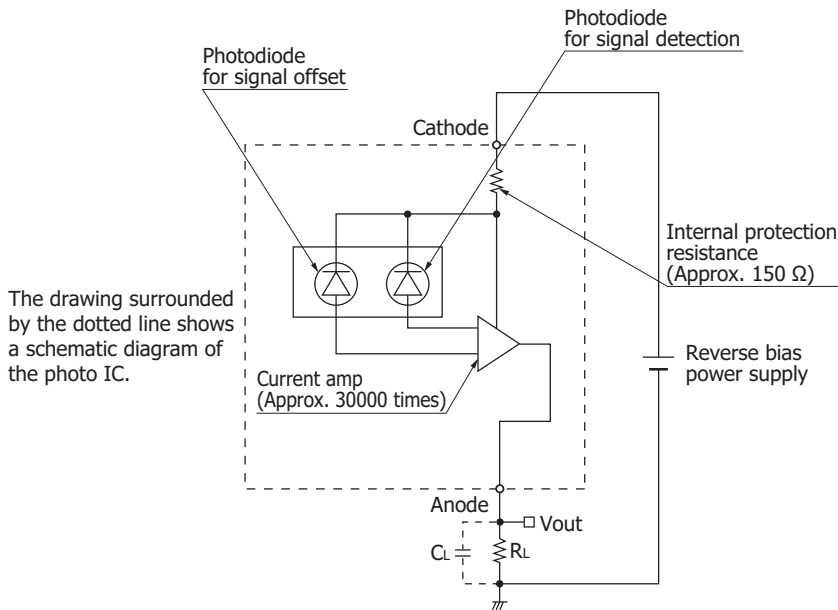
Rise/fall times vs. load resistance



Directivity



Operating circuit example



The photo IC diode must be reverse-biased so that a positive potential is applied to the cathode.

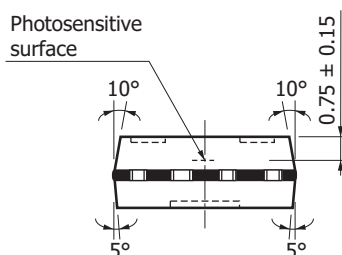
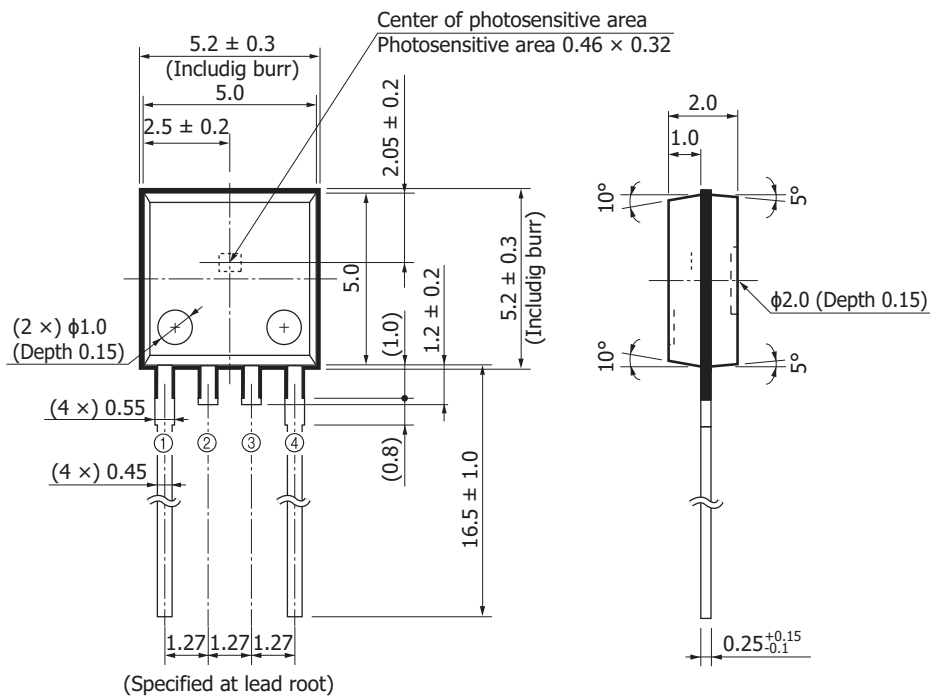
To eliminate high-frequency components, we recommend placing a load capacitance C_L in parallel with load resistance R_L as a low-pass filter.

$$\text{Cutoff frequency (fc)} \approx \frac{1}{2\pi C_L R_L}$$

KP1CC0091EC

Dimensional outlines (unit: mm)

S9066-211SB

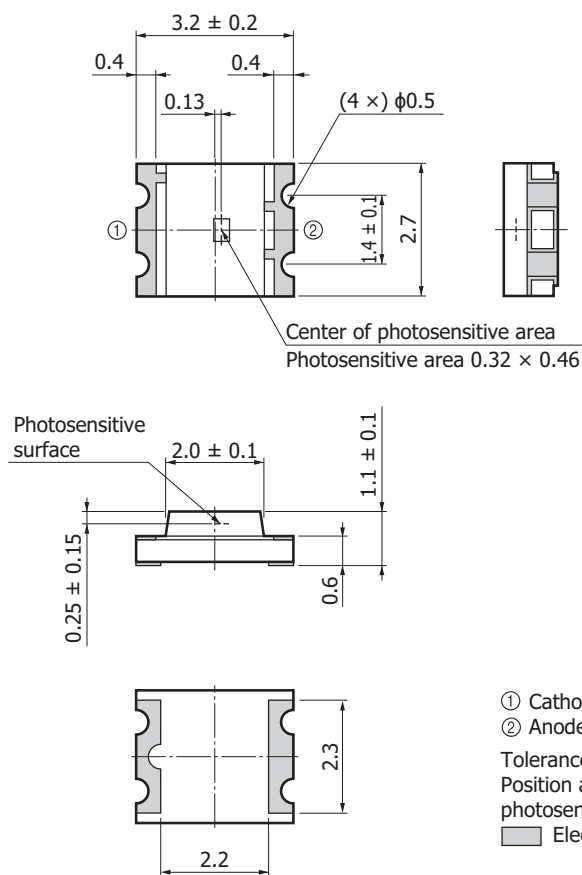


- ① Anode
- ② (Anode)
- ③ NC
- ④ Cathode

Tolerance unless otherwise noted: ±0.1, ±2°
Shaded area indicates burr.
Values in parentheses indicate reference value.

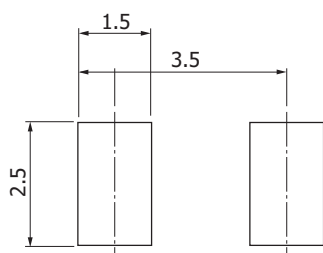
KP1CA0050EE

S9067-201CT



KPICA0051ED

Recommended land pattern (unit: mm, S9067-201CT)



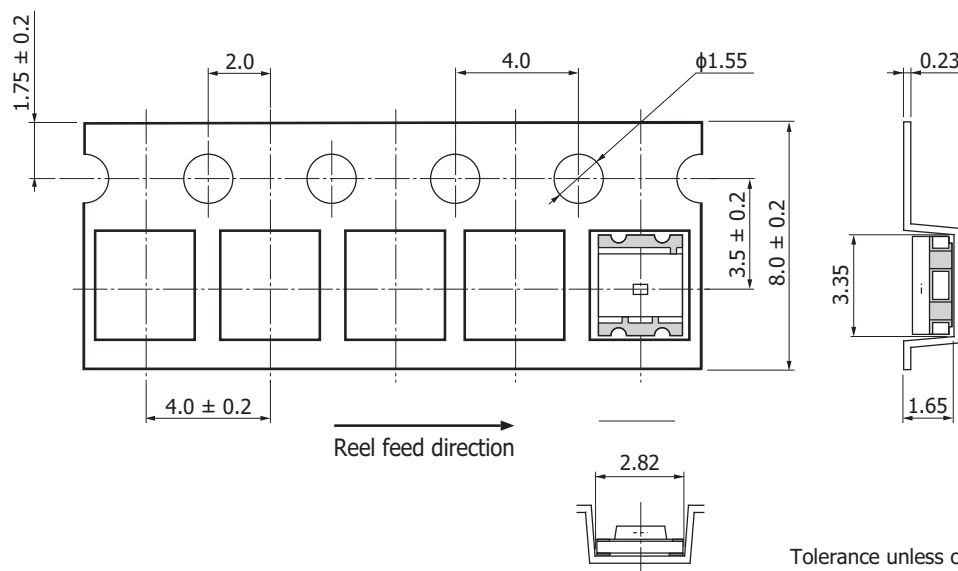
KPICCO222EA

Standard packing specifications (S9607-201CT)

- Reel (conforms to JEITA ET-7200)

Dimensions	Hub diameter	Tape width	Material	Electrostatic characteristics
178 mm	60 mm	8 mm	PS	Antistatic

- Embossed tape (unit: mm, material: PS, antistatic)

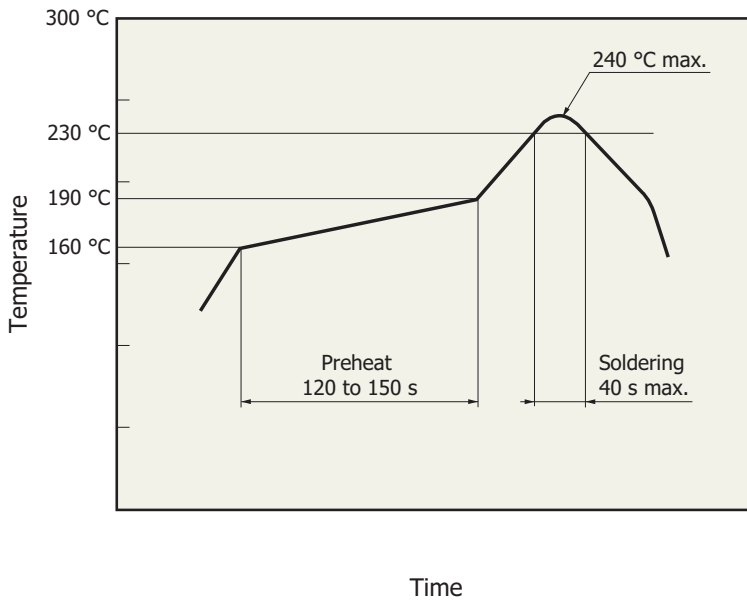


Tolerance unless otherwise noted: ± 0.1

KPIC00226EA

- Packing quantity
2000 pcs/reel
- Packing type
Reel and desiccant in moisture-proof packaging (vacuum-sealed)

Measured example of temperature profile with our hot-air reflow oven for product testing



KPICB0172EA

- The S9607-201CT supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 24 hours.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. Before actual reflow soldering, check for any problems by testing out the reflow soldering methods in advance.

Operating voltage, output characteristics

Figure 2 shows the photocurrent vs. reverse voltage characteristics (light source: LED) for the measurement circuit example in Figure 1. The output curves are shown for illuminance levels. The output curves rise from a reverse voltage (rising voltage) of approximately 0.7 V ($\pm 10\%$).

To protect the photo IC diode from excessive current, a 150 Ω ($\pm 20\%$) protection resistor is inserted in the circuit. Reverse voltage V_R when the photo IC diode is saturated is the sum of $V_{be(ON)}$ and the voltage drop across the protection resistor R_{in} [Equation (1)].

$$V_R = V_{be(ON)} + I_L \times R_{in} \dots\dots\dots (1)$$

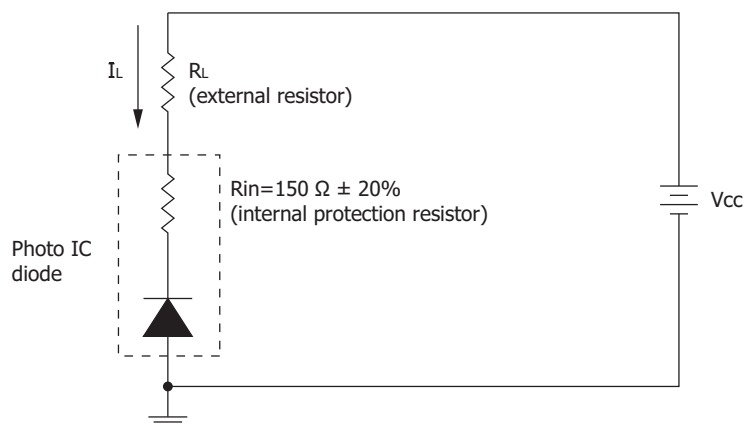
The photodiode's reverse voltage (V_R) is expressed by Equation (2) according to the voltage drop across the external resistor. This is indicated as load lines in Figure 2.

$$V_R = V_{CC} - I_L \times R_L \dots\dots\dots (2)$$

In Figure 2, the intersections between the output curves and the load lines are the saturation points. From these points, the maximum detectable light level can be specified. Since the maximum light level is determined by the supply voltage (V_{CC}) and load resistance (R_L), adjust them according to the operating conditions.

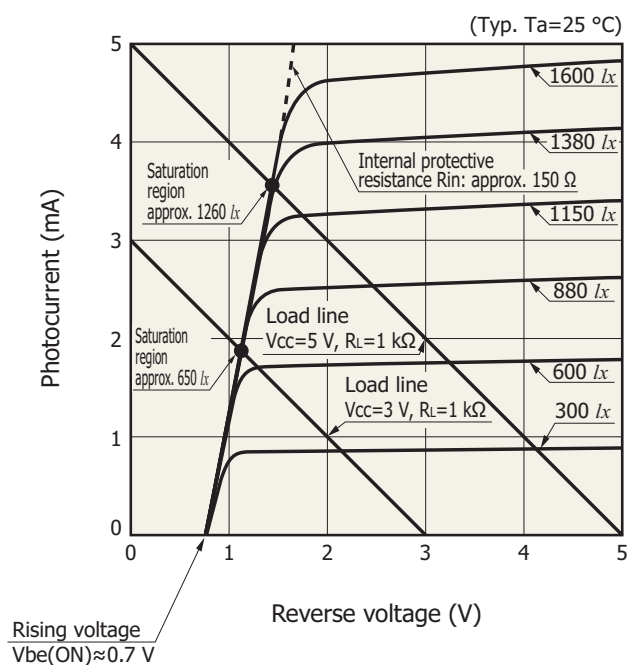
Note: The temperature characteristics of $V_{be(ON)}$ is approximately -2 mV/ $^{\circ}\text{C}$, and that of the protection resistor is approximately $0.1\%/^{\circ}\text{C}$.

[Figure 1] Measurement circuit example



KPICC0128EC

[Figure 2] Photocurrent vs. reverse voltage



KPICB0107EC

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Disclaimer
- Surface mount type products

Information described in this material is current as of August, 2015.

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HAMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trappu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics Italia S.r.l.: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (39) 02-93581733, Fax: (39) 02-93581741

China: Hamamatsu Photonics (China) Co., Ltd.: B1201, Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86) 10-6586-6006, Fax: (86) 10-6586-2866